Formation Principles for Vanadium Selenites: The Role of pH on Product Composition

Jacob H. Olshansky,† Karina J. Wiener,† Matthew D. Smith,† Anahita Nourmahnad,† Max J. Charles,† Matthias Zeller,[‡] Joshua Schrier,[†] and Alexander J. Norquist^{*,†}

† Department of Chemistry, Haverford College, Haverford, Pennsylvania 19[041](#page-7-0), United States

‡ Department of Chemistry, Youngstown State University, Youngstown, Ohio 44555, United States

S Supporting Information

[AB](#page-6-0)STRACT: [A series of](#page-6-0) organically templated vanadium selenites has been prepared under mild hydrothermal conditions. Single crystals of $[C_5H_{14}N_2]$. $[(\text{VO})_3(\text{SeO}_3)_2(\text{HSeO}_3)_4]$, $[C_5H_{14}N_2][\text{VO}(\text{SeO}_3)_2]$, $[(R)$ - $C_5H_{14}N_2$][(VO)₃(SeO₃)₂(HSeO₃)₄], and [(S)- $C_5H_{14}N_2$]- $[(\text{VO})_3(\text{SeO}_3)_2(\text{HSeO}_3)_4]$ were grown from VOSO₄, SeO₂, and 2-methylpiperazine. Controlling the initial pH of the reaction mixture allows for one to select between the compounds found in the $VOSO₄/SeO₂/2$ -methylpiperazine system, as the solution pH directly affects the relative ratio of the $HSeO_3^-$ and SeO_3^{2-} concentrations. Moreover, partial resolution of racemic 2-methylpiperazine is observed in $[C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$, which is understood

through the use of a one-dimensional Ising model. The use of enantiomerically pure 2-methylpiperazine results in fully ordered and fully resolved structures.

INTRODUCTION

A host of new materials has been prepared using hydrothermal and solvothermal reaction conditions during the past few decades.1−⁵ These reaction conditions are especially attractive for exploratory work because they promote the growth of large single c[ry](#page-7-0)s[ta](#page-7-0)ls, can be tuned to accommodate nearly any metal on the periodic table, and offer an astounding amount of phase space to search.⁶ Metal oxides have been the focus of much of this work, owing to their structural diversity, $7,8$ and ability to exhibit technol[og](#page-7-0)ically advantageous properties.⁹

While the formation of new metal oxo co[mpo](#page-7-0)unds has been th[e](#page-7-0) focus of intense research for many years, the *a priori* design of novel materials with specific structures remains elusive, since the mechanisms by which they form are largely unknown.¹⁰ Postulated mechanisms^{4,7,11-13} have led to the elucidation of the reaction influences that most strongly affect the nature [of](#page-7-0) the resulting products. [These](#page-7-0) include (in order of strength) reactant concentrations,^{14−22} charge density matching,^{4,7,23−30} and a series of weaker influences, such as hydrogen-bonding,^{30–32} sterics,^{[9](#page-7-0),29} a[nd](#page-7-0) symmetry.^{33,34} In order [to fully](#page-7-0) understand these influences, a wide range of reaction conditio[ns m](#page-7-0)ust be [exp](#page-7-0)lored through [vari](#page-7-0)ation of reaction parameters such as temperature, time, pH, and reactant choice, all of which are known to affect the primary building units from which the products are formed.⁶

This study is designed to directly probe the effects of reaction mixture pH and reactant conce[nt](#page-7-0)rations on the compositions of the resulting products. A series of organically templated

vanadium selenites containing the $[2\text{-methylpiperazineH}_2]^{2+}$ cations is reported. $[C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ (1a/ 1b) and $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2) were synthesized from racemic sources of 2-methylpiperazine, while $[(R)-C_5H_{14}N_2]$ - $[(VO)_3(SeO_3)_2(HSeO_3)_4]$ (3a) and $[(S)-C_5H_{14}N_2]$ - $[(\text{VO})_3(\text{SeO}_3)_2(\text{HSeO}_3)_4]$ (3b) were grown from enantiomerically pure (R) - $(-)$ -2-methylpiperazine and (S) - $(+)$ -2-methylpiperazine, respectively.

EXPERIMENTAL SECTION

Materials. $VOSO₄$ (97%) was purchased from Aldrich. Se $O₂$ (99.4%), 2-methylpiperazine (2-mpip, 95%), (R)-(−)-2-methylpiperazine $((R)$ -2-mpip, 98+%), and (S) -(+)-2-methylpiperazine $((S)$ -2mpip, 98+%) were purchased from Alfa Aesar. All reagents were used as received. Deionized water was used in these syntheses.

Synthesis. All reactions were conducted in 23 mL poly(fluoroethylene-propylene) lined pressure vessels. Initial reaction pHs were controlled by the addition of 4 M HCl and 4 M NaOH. Reactions were heated to 110 °C and allowed to soak for 24 h. The reactions were then cooled to room temperature at a rate of 6 $^{\circ}$ C·h⁻¹ to promote the growth of large single crystals. Autoclaves were opened in air, and products were recovered through filtration. No additional crystalline or amorphous reaction products were observed.

 $[C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ (1). 1 was synthesized as single crystals through the reaction of 0.1644 g $(1.009 \times 10^{-3} \text{ mol})$ of VOSO₄, 0.6662 g (6.004 × 10⁻³ mol) of SeO₂, 0.3025 g (3.517 × 10⁻³)

Received: July 18, 2014 Published: November 3, 2014

Table 1. Crystallographic Data for Compounds 1a−3b

mol) of 2-mpip, and 5.9980 g (3.33 \times 10⁻¹ mol) of H₂O. Blue blocks were produced in 79.6% yield (based upon V). IR data (cm[−]¹): N−H, 1441, 1466, 1572; C-H, 3027; O-H, 3431; V=O, 965; Se-O, 814. EA obsd (calc): C 5.82% (5.61%), H 1.47% (1.70%), N 2.57% (2.60%), Se 37.7% (44.3%), V 13.3% (14.3%).

 $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2). 2 was synthesized as single crystals through the reaction of 0.3234 g (1.984 \times 10⁻³ mol) of VOSO₄, 0.5607 g (5.053 × 10⁻³ mol) of SeO₂, 0.4065 g (4.727 × 10⁻³ mol) of 2-mpip, and 3.378 g (1.88×10^{-1} mol) of H₂O. Aquamarine plates were produced in 27.8% yield (based upon V). IR data (cm[−]¹): N−H, 1452, 1618; C-H, 3007; O-H, 3449; V=O, 982; Se-O, 810. EA obsd (calc): C 14.33% (14.19%), H 1.75% (3.3%), N 2.5% (6.6%), Se 41.66% (37.3%), V 13.77% (12.0%).

 $[(R)-C_5H_{14}N_2]$ [(VO)₃(SeO₃)₂(HSeO₃)₄] (3a). 3a was synthesized as single crystals through the reaction of 0.1624 g (9.96 \times 10⁻⁴ mol) of VOSO₄, 1.5624 g (1.408 × 10⁻² mol) of SeO₂, 0.0537 g (6.24 × 10⁻⁴) mol) of (R)-2-mpip, and 5.292 g (2.94 \times 10⁻¹ mol) of H₂O. Blue blocks were produced in 73.2% yield (based upon V). IR data (cm^{-1}) : N−H, 1440, 1466, 1575; C−H, 3029; O−H, 3421; V=O, 966; Se−O, 854. EA obsd (calc): C 5.61% (5.61%), H 1.72% (1.70%), N 2.58% (2.60%), Se 43.73% (44.3%), V 13.92% (14.3%).

 $[(S)-C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ (3b). 3b was synthesized as single crystals through the reaction of 0.1655 g (1.015 \times 10⁻³ mol) of VOSO₄, 1.5661 g (1.411 × 10⁻² mol) of SeO₂, 0.104 g (1.209 × 10⁻³) mol) of (S)-2-mpip, and 5.9500 g (3.310 \times 10⁻¹ mol) of H₂O. Blue blocks were produced in 84.2% yield (based upon V). IR data (cm^{-1}) : N−H, 1440, 1466, 1573; C−H, 3027; O−H, 3420; V=O, 966; Se−O, 854. EA obsd (calc): C 5.41% (5.61%), H 1.68% (1.70%), N 2.89% (2.60%), Se 41.88% (44.3%), V 13.53% (14.3%).

Single Crystal X-ray Diffraction. Data were collected using a Bruker AXS Smart Apex CCD diffractometer with Mo K α radiation (λ $= 0.71073$ Å). A single crystal was mounted on a Mitegen micromesh mount using a trace of mineral oil and cooled in situ to $100(2)$ K for data collection. Frames were collected, reflections were indexed and processed, and the files were scaled and corrected for absorption using APEX2.³⁵ The heavy atom positions were determined using SIR92.³⁸ All other non-hydrogen sites were located from Fourier difference maps. [All](#page-7-0) non-hydrogen sites were refined using anisotropic ther[mal](#page-7-0) parameters using full matrix least-squares procedures on F_o^2 with $I >$ $3\sigma(I)$. Hydrogen atoms were placed in geometrically idealized positions. All calculations were performed using Crystals v. 14.23c.³⁷ Relevant crystallographic data are listed in Table 1. A figure displaying the positions of the largest peak and hole in the difference map f[or](#page-7-0) compound 2 can be found in the Supporting Information.

Powder X-ray Diffraction. Powder diffraction patterns were recorded on a GBC-Difftech MMA powder diffractometer. Dry powdered samples were packed [into](#page-6-0) [sample](#page-6-0) [holders.](#page-6-0) Calculated powder patterns were generated from single crystal data using ATOMS v. 6.0.³⁸ Powder X-ray diffraction patterns were consistent with patterns predicted from the refined structures of 1−3. No evidence of ad[diti](#page-7-0)onal phases was observed. Experimental powder Xray diffraction patterns match patterns simulated from single crystal diffraction data.

Infrared Spectroscopy. Infrared measurements were obtained using a PerkinElmer FT-IR Spectrum 1000 spectrophotometer. Samples were diluted with spectroscopic grade KBr and pressed into pellets. Scans were collected over the range of 400–4000 cm⁻¹. .

Bond Valence Sums. The hydrogen-bonding networks present in all compounds were analyzed using bond valence sums.³⁹ All calculations were performed using parameters compiled by Brese and O'Keeffe.⁴⁰ Complete tables of bond valence sums fo[r](#page-7-0) each compound are available in the Supporting Information.

Electronic [S](#page-7-0)tructure Calculations. Solid-state electronic structure calculations were perform[ed using ABINIT v. 6.4.1](#page-6-0).^{41,42} ABINIT calculations used the Perdew−Burke−Ernzerhof generalized gradient approximation (PBE-GGA) exchange-correlation func[tiona](#page-7-0)l, normconserving Troullier−Martins pseudopotentials, a planewave basis set with energy cutoff of 25 hartree, a 6 × 6 × 6 Monkhorst–Pack k-point sampling grid, and experimental crystal structures. Electron localization functions (ELFs) were calculated from the self-consistent valence electron densities and visualized using Vesta v. 3.1.8.⁴³ Partial atomic charge determinations were performed using the iterativeHirshfeld scheme (Hirshfeld-I)^{44,45} on the self-consisten[t v](#page-7-0)alence electron density using the Cut3D program and promolecular allelectron atomic charge densi[ties](#page-7-0) were using the HF96 atomic Hartree–Fock code⁴⁶ following the method described in our previous work.9,29,31,47,48

■ RESULTS AND DISCUSSION

The inorganic components in compounds 1−3b are all constructed from similar primary building units. Compounds **1, 3a, and 3b** contain $[\text{VO}_5]$, $[\text{VO}_6]$, $[\text{HSeO}_3]^-$, and $[\text{SeO}_3]^{2-}$ moieties, while 2 only contains $[VO₅]$ and $[SeO₃]²⁻$ groups. The V $-O_{\text{terminal}}$ bond lengths range between 1.582(8) and 1.6189(4) Å, while the V-O_{bridging} bonds are longer, between 1.863 (8) and 2.215 (3) Å. Se $-\text{O}_{\text{bridging}}$ bond lengths are observed between 1.660(3) and 1.731(5) Å. Se−O(H) bonds are longer, with distances between $1.754(6)$ and $1.7918(4)$ Å. The bond valence sums for vanadium and selenium range between 3.93 and 4.10 vu and between 3.87 and 4.17 vu, respectively. Complete tables of bond lengths and angles can be found in .cif format in the Supporting Information.

 $[C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ (1) contains a threedimensional inorganic framework and $[2\text{-mpipH}_2]^{2+}$ cations. The $\left[2\text{-mpipH}_2\right]^{2+}$ cations reside in channels within the framework, as shown in Figure 1. The framework is constructed

Figure 1. Three-dimensional packing of $[C_5H_{14}N_2]$ - $[(\text{VO})_3(\text{SeO}_3)_2(\text{HSeO}_3)_4]$ (1). Green polyhedra represent $[\text{VO}_6]$ and $[VO₅]$, while purple, red, blue, white, and gray spheres represent selenium, oxygen, nitrogen, carbon, and hydrogen, respectively. Organic ammonium cation hydrogen atoms have been omitted for clarity.

from two distinct components. $[(VO)(SeO₃)(HSeO₃)]$ chains, which extend along the [1 1 0] direction, form hydrogenbonded pseudolayers. Similar chain connectivities have been observed in a series of metal selenites.^{49,50} $[(\text{VO})(\text{HSeO}_3)_2]$ groups act as pillars between the pseudolayers, forming the three-dimensional framework. Compo[und](#page-7-0) 1 was synthesized from a racemic mixture of 2-mpip. Partial resolution of the $[(R)-2-mpipH₂]²⁺$ and $[(S)-2-mpipH₂]²⁺$ cations is observed, which is discussed below. Crystallographic disorder is observed in both the organic ammonium cations and $[VO₅]$ square pyramids.

 $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2) contains $[VO(SeO_3)_2]_n^{2n-1}$ layers separated by $[2\text{-mpipH}_2]^{2+}$ cations. See Figure 2. The $[\text{VO(SeO}_3)_2]_n^{2n}$ layers in 2 are similar to those observed in $(\mathrm{H_3NCH_2CH_2NH_3})[\mathrm{VO(SeO}_{3/2}]$, a related phase containing ethylenediammonium cations.⁵¹ Additional analogues are found in both organically templated compounds 52 and inorganic phases.53−⁵⁵ Compound 2 ex[ists](#page-7-0) as an inversion twin, in which the $[(R)-2-mpipH₂]²⁺$ and $[(S)-2-mpipH₂]²⁺$ cations are segreg[ated i](#page-8-0)nto domains within each crystal. The Hirshfeld-I

Figure 2. Views of the (a) $[VO(SeO₃)₂]_n²ⁿ⁻ layers and (b) three$ dimensional packing for $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2). ELF isosurfaces are shown with a boundary condition of 0.96. Green polyhedra represent $[VO₅]$, while purple, red, blue, and white spheres represent selenium, oxygen, nitrogen, and carbon, respectively. Hydrogen atoms have been omitted for clarity.

scheme^{44,45,56} was used to determine partial atomic charges for all atoms; a complete table of partial atomic charges for 2 is availabl[e in](#page-7-0) [th](#page-8-0)e Supporting Information. As 2 crystallizes in the chiral and polar space group P1 (No. 1), the magnitudes and directions of b[oth component and net](#page-6-0) dipole moments were calculated.^{9,29,30,47,57–59} See Figure 3 and Table 2. Pseudoinversion within the inorganic component is observed, with a near canc[ellation i](#page-7-0)[n the](#page-8-0) dipole mom[en](#page-3-0)t of the $\left[VO(SeO₃)₂ \right]_n^{2n-1}$ $\left[VO(SeO₃)₂ \right]_n^{2n-1}$ $\left[VO(SeO₃)₂ \right]_n^{2n-1}$ layers. The $[(R)$ -2-mpip $\tilde{H_2}]^{2+}$ cations, in contrast, are roughly aligned with the b-axis and make the largest contribution to the net dipole moment.

Compounds 1 and 2 were synthesized from the $VOSO_4/$ $SeO₂/2$ -mpip system. We recently published another compound from this system, $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2$. $2H₂O₂³⁰$ which is constructed from the same primary building units as 1 and 2, and exhibits a three-dimensional inorganic frame[wo](#page-7-0)rk that is distinctly different from that in 1. The major differences between these compounds stem from the ratios of components, as summarized in Table 3. As three compounds with different stoichiometries and structures were synthesized from the same reactants under nearly [id](#page-3-0)entical conditions, the influences that direct formation of each compound were investigated and elucidated.

During the past several years, we have observed a hierarchy of influences that affect the formation of organically templated metal oxides. The primary influence in these reactions is the relative concentration of each reactive species. The identities of these primary building units are dictated by experimental

Figure 3. Ball-and-stick representation of 2. Arrows indicate the approximate directions and magnitudes of the dipole moments for $[\text{VO}_5]$, $[\text{SeO}_3]$, and $[\text{C}_5\text{H}_{14}\text{N}_2]^{\text{2+}}$ cations. The large black arrow represents the direction of the net dipole moment for 2. Hydrogen atoms have been omitted for clarity.

Table 2. Calculated Component and Net Dipole Moments for $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2)

species	dipole moment (D)
$V(1)O_5$	3.87
$Se(1)O_3$	9.12
Se(2)O ₃	9.04
$[VO(SeO3)2]2- layer$	0.53
$[2\text{-mpipH}_2]^{2+}$ cation	2.69
net	2.42

Table 3. Composition Ratios in $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2$ ²H₂O, $[C_{5}H_{14}N_{2}][(VO)_{3}(SeO_{3})_{2}(HSeO_{3})_{4}]$ (1), and $[C_5H_{14}N_2][VO(SeO_3)_2]$ (2)

parameters, such as pH, temperature, and even reactant choice. The relative concentrations of the reactive species also directly influence composition and structure.^{14−21,29,31} The secondary influence is charge density matching^{4,7} between the inorganic anionic and organic cationic compo[nents of t](#page-7-0)hese reactions. While the charge densities of the [orga](#page-7-0)nic cations are largely fixed by solution pH, as that dictates their protonation states, the inorganic components can access a range of charge densities through the formation of different secondary building units (SBUs).^{27,28,31} Several weaker tertiary influences have also been observed, which neither dictate the compositions of the

compounds nor control the connectivities of their respective SBUs. Instead, they generally affect local bonding interactions and involve subtle structural parameters, such as hydrogen bonding,^{31,32,48} sterics,³³ or symmetry.^{12,14–16,22,33,34} The effects of reactant concentrations as a primary influence are clearly [observed](#page-7-0) in th[e](#page-7-0) work reported [here](#page-7-0), [through](#page-7-0) their manipulation using both initial pH and reaction mixture compositions. In addition, tertiary infleunces are observed in the partial resolution of racemic 2-mpip in 1.

The effects of reactant concentrations in the $VOSO₄/SeO₂/$ 2-mpip system were explored in two ways. First, three series of reactions were conducted, each of which contained a specific fixed V:Se:amine ratio. Second, the initial solution pH was varied between 1 and 7 for each V:Se:amine ratio. Distinct crystallization fields for 1, 2, and $[C_5H_{14}N_2][VO(SeO_3)$ - $(HSeO₃)$ ₂·2H₂O are observed throughout this range of reaction conditions, as shown in Figure 4.

The initial solution pH of each reaction mixture affects the relative phase stabilities of 1, 2, and $[C_5H_{14}N_2][VO(SeO_3) [C_5H_{14}N_2][VO(SeO_3) [C_5H_{14}N_2][VO(SeO_3) (HSeO₃)$ ₂.2H₂O. The [HSeO₃]⁻:[SeO₃]^{2–} ratio varies in the three compounds observed in the $VOSO₄/SeO₂/2$ -mpip system. See Table 3. 1 is the most $[\mathrm{HSeO}_{3}]^{-}$ rich compound in the system with a $[HSeO₃]⁻: [SeO₃]²⁻$ ratio of 2:1. $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2.2H_2O$, in contrast, contains an equal number of $[\mathrm{HSeO}_3]^-$ and $[\mathrm{SeO}_3]^{2-}$ groups. 2 only contains $\text{[SeO}_3]^{\text{2-}}$ and is the most $\text{[SeO}_3]^{\text{2-}}$ rich compound. 1 is observed at low pH conditions, under which $[\mathrm{HSeO}_{3}]^-$ is stabilized with respect to $\text{[SeO}_3]^{\text{2-}}$. As the initial solution pH increases, so does the relative concentration of $\text{[SeO}_3]^{\text{2-}}$ with respect to $[\mathrm{HSeO}_{3}]^{\text{-}}$. This causes a shift in phase stability to $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2.2H_2O$, which contains an equal amount of $[HSeO₃]⁻$ and $[SeO₃]²$. 2, which only contains $\left[\text{SeO}_3\right]^{2-}$, is only observed from reactions with the highest initial solution pHs. Clearly, the relative concentrations of $[HSeO₃]^{2–}$ and $[SeO₃]^{2–}$ in solution are reflected in the compositions of the resulting compounds.

The relative phase stabilities of 1, 2, and $[C_5H_{14}N_2][VO (SeO₃)(HSeO₃)₂·2H₂O$ are also affected by the initial concentrations of vanadium, selenium, and 2-mpip. See Figure 4. The crystallization fields of these three compounds shift as the initial reaction mixture is changed from $1 \nabla : 8 \nabla e : 1$ amine [to](#page-4-0) $1 \nabla : 6 \nabla e : 3$ amine, a change in which the initial amine concentration is drastically increased. 2 is the most amine rich compound, with a V:Se:amine ratio of 1:2:1, while $[C_5H_{14}N_2]$ - $[VO(SeO₃)(HSeO₃)]₂·2H₂O$ and 1 are both more vanadium deficient. As such, increasing the initial amine concentration stabilizes the formation of 2 with respect to $[C_5H_{14}N_2][VO (SeO₃)(HSeO₃)$]₂·2H₂O and 1, and causes the crystallization field of 2 to increase. Likewise, $[C_5H_{14}N_2][VO(SeO_3)$ - $(HSeO₃)$ ₂·2H₂O is stabilized with respect to 1, owing to the low amine concentration in 1. This causes an analogous shift in the crystallization field of $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2$. $2H₂O$ to lower pHs, and results in cocrystallization of 1 and $[C_5H_{14}N_2][VO(SeO_3)(HSeO_3)]_2.2H_2O$ at pH 2 (shown as green in Figure 4).

The results of doubling the vanadium concentration are shown in the [2](#page-4-0) V:5 Se:3 amine portion of Figure 4. The crystallization field corresponding to compound 2 is no longer observed because this compound, which has the [l](#page-4-0)owest vanadium concentration, is destabilized by the vanadium rich reaction mixture. The crystallization fields of 1 and $[C_5H_{14}N_2]$ - $[VO(SeO₃)(HSeO₃)]₂·2H₂O$ do not change appreciably.

Figure 4. Plot of the product composition as a function of solution pH and initial reaction mixture composition in the VOSO $_4$ /SeO $_2$ /2-mpip/H₂O system.

The phase stabilities of 1, 2, and $[C_5H_{14}N_2][VO(SeO_3) (HSeO₃)$ ₂·2H₂O are directly affected by the concentrations of the primary building units, from which they are formed. These effects were directly observed either by changing the initial vanadium, selenium, and amine concentration or by changing the protonation state of the selenous acid by altering the initial reaction pH. The relative concentrations of the primary building units are the strongest influence over the composition and structure of the resulting compounds.

1 was synthesized from a racemic mixture of (R) -2-mpip and (S)-2-mpip. Disorder is present in the crystallographic structure of 1, in which an $[(R)$ -2-mpip $H_2]^{2+}$ and an $[(S)$ -2-mpip $H_2]^{2+}$ cation roughly occupy the same site of the structure. The central piperazinium rings in the $[(R)-2$ -mpip $H_2]^{2+}$ and $[(S)-2$ mpip H_2 ²⁺ cations are not superimposed. Instead, each atom in each cation resides on its own site, as shown in Figure 5. Disorder is also present in the $[V(3)O₅]$ and $[V(4)O₅]$ polyhedra. The $[(R)-2-\text{mpipH}_2]^2$ ⁺ and $[(S)-2-\text{mpipH}_2]^2$ ⁺ cations in 1 are not related to one another through any symmetry operation, making this compound a group 2

Figure 5. Disorder mechanism for the $[C_{5}H_{14}N_{2}]^{2+}$ cations and the $[VO₅]$ polyhedra in 1. Hydrogen atoms on the organic cations have been omitted for clarity.

kryptoracemate, as defined by Brock et al. 60 In addition, the populations of $[(R)$ -2-mpip $H_2]^{2+}$ and $[(S)$ -2-mpip $H_2]^{2+}$ within each crystal differ; they are not present in [a](#page-8-0) 1:1 ratio, despite the crystals being grown from a solution containing a racemic mixture of 2-mpip. Single crystal X-ray diffraction data were collected on seven different crystals of 1. The results of population refinements of the $[(R)$ -2-mpip $H_2]^{2+}$ and $[(S)$ -2- $\text{mpipH}_{2}]^{2+}$ cations in these seven crystals are summarized in Table 4. While there is no preference for either $[(R)-2-$

mpipH₂]²⁺ or $[(S)-2-mpipH₂]²⁺$, the cations consistently appear in a ratio of ∼2:1. The mean and median ratios are 68.2:31.8 and 67.7:32.3, respectively. The structures denoted 1a and 1b in Table 1 represent results from two different single crystals, one of which contains more $[(R)$ -2-mpip $H_2]^{2+}$ (1a), while the other [co](#page-1-0)ntains more $[(S)$ -2-mpip $H_2]^{2+}$ (1b). The structures of the other five single crystals are essentially identical to either 1a or 1b, and so their inclusion would be redundant.

The partial resolution of the (R) -2-mpip and (S) -2-mpip in the formation of 1 prompts two questions. First, what is the basis for the resolution of (R) -2-mpip and (S) -2-mpip in this reaction? Second, can enantiomerically pure analogues be formed and can their structures help explain the partial resolution in 1? In order to address these questions, reactions using enantiomerically pure sources of either (R) -2-mpip or (S)-2-mpip were conducted. The results of these reactions are $[(R)-C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ (3a) and $[(S)-C_5H_{14}N_2][(VO)_3(SeO_3)_2(HSeO_3)_4]$ $C_5H_{14}N_2$][(VO)₃(SeO₃)₂(HSeO₃)₄] (3b). See Figure 6.

3a and 3b crystallize in P1 (No. 1), and the Flack parameters indicate well-resolved absolute structures, with v[alu](#page-5-0)es of $0.027(8)$ and $0.034(8)$ for 3a and 3b, respectively. There is

Figure 6. Three-dimensional packing figures for 3a and 3b. Green polyhedra represent $[VO_6]$ and $[VO_5]$, while purple, red, blue, white, and gray spheres represent selenium, oxygen, nitrogen, carbon, and hydrogen, respectively. Organic ammonium cation hydrogen atoms have been omitted for clarity.

no crystallographic disorder in either the inorganic or organic components of these compounds. The orientations of the $[VO₅]$ pillars are resolved, as shown in Figure 6. Dipole moment calculations were performed on 3a and 3b, with results summarized in Table 5. Pseudoinversion symmetry is observed in the component dipole moments of $[V(2)O_6]$, $[V(3)O_6]$, and all $\left [\text{SeO}_{3} \right]^{\mathcal{I}^-}$ and $\left [\text{HSeO}_{3} \right]^-$ groups, as shown in Figure 7. The component moment of $[V(1)O_5]$ makes the largest contribution to the net framework moments, which are calculate[d](#page-6-0) to be 4.03 and 2.99 D for 3a and 3b, respectively. The dipole moments on the $[2\text{-mpipH}_2]^{2+}$ cations are roughly anti-aligned with respect to the $[\overline{V(1)}O_5]$ square pyramids, resulting in net compound moments of 2.70 and 2.23 D for 3a and 3b, respectively. Differences in dipole moments of this magnitude within pairs of enantiomer structures are common. $\frac{\cancel{5},29,30,47}{\cancel{5}}$ These differences are generally caused by asymmetric charge distributions on the $[(R)$ -2-mpip $H_2]^{2+}$ $H_2]^{2+}$ $H_2]^{2+}$ and $[(S)$ -2-mpip $H_2]^{2+}$ cations and the orientation of O−H bonds in the $[\widetilde{\mathrm{HSeO}}_3]^$ groups.

The structures of 3a and 3b provide useful information to understand the partial resolution of the organic ammonium

cations in 1. The disorder of the $[2\text{-mpipH}_2]^{2+}$ cations and $[VO₅]$ polyhedra is not fully random. Instead, a partial ordering scheme is present in which the chirality of the $[2\text{-mpipH}_{2}]^{2+}$ cations and the orientations of the $[VO₅]$ polyhedra are conserved within the *ab* plane. An $[(R)-2-\text{mpip}H_2]^{2+}$ and an $[(S)$ -2-mpip $H_2]$ ²⁺ cation cannot sit next to one another within a given channel owing to steric repulsions between the methyl groups. Moreover, the position of the methyl group on a given $[2\text{-mpipH}_2]^{2+}$ cation directly affects the orientations of the adjacent $[VO₅]$ groups. This partial ordering scheme is also supported by the structures of 3a and 3b. The correlation between amine chirality and $[VO_{5}]$ polyhedron orientation in the partial ordering scheme is directly observed in these fully resolved structures. A figure of these interactions is provided in the Supporting Information. The disorder must come from weak correlations along the c-axis.

Diff[erences in the three](#page-6-0)-dimensional hydrogen-bonding networks exist between fully resolved and mixed enantiomer compounds. The ring structures of the $[(R)$ -2-mpip $\mathrm{H}_2]^{2+}$ and $[(S)-2-mpipH₂]²⁺$ cations in 1 are not superimposed. See Figure 5. As a result, the nature of the hydrogen-bonding interactions between the cation and inorganic framework depend[s](#page-4-0) upon the local chirality. N1 and N3, the nitrogen atoms closest to the methyl groups, form hydrogen bonds that are ∼0.1 Å longer than those from N2 and N4. A figure of these interactions, with distances, is provided in the Supporting Information. This asymmetry results in distinct differences between systems in which consecutive layers ha[ve a single](#page-6-0) [chirality vers](#page-6-0)us layers in which the chirality changes.

The partial enantiomeric resolution can be further understood in terms of the Ising model,

$$
\hat{H} = \sum_{i} B_i s_i + \sum_{i,j} J_{ij} s_i s_j \tag{1}
$$

where each of the unit cell sites, i, is modeled by an effective "spin" s_{i} , (e.g., denoting $[(R)-2-mpipH_2]^{2+}$ and $[(S)-2$ mpipH₂]²⁺ containing sites as $s_i = +1$ and $s_i = -1$, respectively), B_i denotes a site-specific bias energy, and J_{ij} denotes the interaction between spins at sites i and j . Based on the equal occurrence of $[(R)-2-mpipH₂]²⁺$ -predominant and $[(S)-2$ $mpipH_{2}]^{2+}$ -predominant crystals, it is assumed that an initial seed nucleus is chosen randomly, with equal probabilities for $[(R)$ -2-mpip $H_2]$ ²⁺ and $[(S)$ -2-mpip $H_2]$ ²⁺ containing sites, so B_i = 0. Subsequent growth of the crystal then depends on this

Figure 7. Ball-and-stick representations of 3a and 3b. Arrows indicate the approximate directions and magnitudes of the dipole moments for $[VO₆]$, $[VO₅]$, $[SeO₃]$, and $[C₅H₁₄N₂]²⁺$ cations. The large black arrow represents the direction of the net dipole moment for 3a and 3b. Organic ammonium cation hydrogen atoms have been omitted for clarity.

seed nucleus. The proposed enantiomeric ordering within a two-dimensional layer, based upon interatomic distances and the structures of 3a and 3b, indicates that adjacent sites are strongly biased toward containing the same enantiomer, as discussed above. In the Ising model, this corresponds to a ferromagnetic ordering $(J_{ii} < 0)$ with a large $|J_{ii}|$ for the intralayer interaction. The low crystallographic ordering between the layers indicates that adjacent layers have a preference for containing the same enantiomer, but that a significant fraction of sites contains a different enantiomer. The overall preference for preserving the same enantiomeric ordering (approximately 2:1) indicates that the interlayer coupling also corresponds to a ferromagnetic $(J_{ij} < 0)$ Ising model, but with a smaller $|J_{ij}|$ allowing thermal fluctuations to give rise to disorder.

As perfect ordering within the ab plane is assumed, owing to strong intralayer interactions, the problem reduces to the onedimensional Ising model,

$$
\hat{H} = J \sum_{i} s_i s_{i+1} \tag{2}
$$

where *J* is the interlayer coupling (assumed to occur only between nearest neighbors along the interlayer axis, and with uniform strength). The probability, p , of observing flipped (nonmajority) spins is

$$
\ln \frac{p}{1-p} = \frac{-2J}{k_B T} \tag{3}
$$

where k_B is the Boltzmann constant and T is the absolute temperature. The crystals were grown at $T = 110$ °C or $k_B T =$ 33 meV. The mean probability of observing a "flipped" spin is $p = 0.318$, based upon the seven single crystal structures obtained for 1, shown in Table 4. From this, the effective interaction energy is found to be $J = 13$ meV.

The 1D-Ising model allows u[s](#page-4-0) to better understand our results. First, unlike the 2D-Ising model, there are no phase transitions; this is consistent with the range in enantiomer ratios shown in Table 4. Second, the pair correlation function, $\langle s_i s_j \rangle$, of the 1D-Ising model decays exponentially with the distance between the [sit](#page-4-0)es |i−j| at any finite temperature. This suggests that domain sizes should be small. Alternatively, if domain sizes were large, and the $[(R)$ -2-mpip $H_2]$ ²⁺ and $[(S)$ -2mpip H_2 ²⁺ were segregated into macroscopic domains within each crystal, crystallographic disorder would not be observed. These ordered structures would have Flack parameters deviating strongly from either 0 or 1, indicating an inversion twin. Thus, the small Flack parameters for 1a and 1b, shown in Table 3, are consistent with the small domain size predicted by the 1D-Ising model. Third, the 1D-Ising model allows us to put a bo[un](#page-3-0)d on the possibility of modifying the overall enantiomeric preference by controlling the synthetic conditions. The hydrothermal synthesis of 1 can be performed between 90 and 125 °C, which in turn limits p to 0.30 and 0.32, respectively. Changing the temperature would have a relatively insignificant impact on the enantiomeric preference.

■ CONCLUSION

A direct correlation between the concentrations of the primary building units and product compositions is observed in the VOSO4/SeO2/2-methylpiperazine system. Adjustment of the initial reaction pH can be used to alter the ratio between $[HSeO₃]⁻$ and $[SeO₃]²$, controlling the composition of the reaction product. In addition, partial resolution of $[(R)-2$ mpip $H_2]^{2+}$ and $[(S)$ -2-mpip $H_2]^{2+}$ is caused by small differences in hydrogen-bonding interactions.

■ ASSOCIATED CONTENT

3 Supporting Information

Figures of the cation−anion interactions in 1, 3a, and 3b, powder X-ray diffraction data and tables of bond valence sums for all compounds, and Hirshfeld-I partial atomic charges for 2, 3a, and 3b. An X-ray crystallographic information file (CIF) for 1a, 1b, 2, 3a, and 3b. This material is available free of charge via the Internet at http://pubs.acs.org.

■ AUTHOR INFORMATION

Corresponding Author

*Haverford College, 370 Lancaster Avenue, Haverford, PA 19041, United States. Tel: (610) 896 2949. Fax: (610) 896 4963. E-mail: anorquis@haverford.edu. http://www.haverford. edu/chem/Norquist/.

Notes

[The authors declare n](http://www.haverford.edu/chem/Norquist/)[o](mailto:anorquis@haverford.edu) [competing](mailto:anorquis@haverford.edu) fina[ncial](http://www.haverford.edu/chem/Norquist/) [interest.](http://www.haverford.edu/chem/Norquist/)

■ ACKNOWLEDGMENTS

The authors acknowledge support from the NSF (Award No. DMR-1307801), the Henry Dreyfus Teacher-Scholar Awards Program, and grants to Haverford College from the HHMI Undergraduate Science Education Program. M.Z. acknowledges support for the purchase of a diffractometer from the NSF Grant 0087210, the Ohio Board of Regents Grant CAP-491, and Youngstown State University. This research used computational resources of the National Energy Research Scientific Computing Center (NERSC), which is supported by the Office of Science of the U.S. Department of Energy under Contract No. DE-AC02-05CH11231.

REFERENCES

(1) Cheetham, A. K.; Ferey, G.; Loiseau, T. Angew. Chem., Int. Ed. 1999, 38, 3268−3292.

(2) Cundy, C. S.; Cox, P. A. Chem. Rev. 2003, 103, 663−701.

(3) Haushalter, R. C.; Mundi, L. A. Chem. Mater. 1992, 4, 31−48.

(4) Ferey, G. J. Fluorine Chem. 1995, 72, 187−193.

(5) Rao, C. N. R.; Natarajan, S.; Neeraj, S. J. Am. Chem. Soc. 2000, 122, 2810−2817.

(6) Rabenau, A. Angew. Chem., Int. Ed. Engl. 1985, 24, 1026−1040.

(7) Ferey, G. Chem. Mater. 2001, 13, 3084−3098.

(8) Rao, C. N. R.; Behera, J. N.; Dan, M. Chem. Soc. Rev. 2006, 35, 375−387.

(9) Glor, E. C.; Blau, S. M.; Yeon, J.; Zeller, M.; Shiv Halasyamani, P.;

Schrier, J.; Norquist, A. J. J. Solid State Chem. 2011, 184, 1445−1450. (10) Yu, J.; Xu, R. Acc. Chem. Res. 2010, 43, 1195−1204.

(11) Rao, C. N. R.; Natarajan, S.; Choudhury, A.; Neeraj, S.; Ayi, A. A. Acc. Chem. Res. 2001, 34, 80−87.

(12) Murugavel, R.; Walawalkar, M. G.; Dan, M.; Roesky, H. W.; Rao, C. N. R. Acc. Chem. Res. 2004, 37, 763−774.

- (13) Rao, C. N. R.; Dan, M.; Behera, J. N. Pure Appl. Chem. 2005, 77, 1655−1674.
- (14) Halasyamani, P.; Willis, M. J.; Stern, C. L.; Lundquist, P. M.;
- Wong, G. K.; Poeppelmeier, K. R. Inorg. Chem. 1996, 35, 1367−1371.
- (15) Norquist, A. J.; Heier, K. R.; Stern, C. L.; Poeppelmeier, K. R. Inorg. Chem. 1998, 37, 6495−6501.
- (16) Thomas, P. M.; Norquist, A. J.; Doran, M. B.; O'Hare, D. J. Mater. Chem. 2003, 13, 88−92.

(17) Veltman, T. R.; Stover, A. K.; Narducci Sarjeant, A.; Ok, K. M.;

Halasyamani, P. S.; Norquist, A. J. Inorg. Chem. 2006, 45, 5529−5537. (18) Nelson, J. H.; Johnston, A. R.; Narducci Sarjeant, A.; Norquist,

A. J. Solid State Sci. 2007, 9, 472−484.

(19) Norquist, A. J.; Doran, M. B.; Thomas, P. M.; O'Hare, D. Dalton Trans. 2003, 1168−1175.

(20) Stover, A. K.; Gutnick, J. R.; Narducci Sarjeant, A.; Norquist, A. J. Inorg. Chem. 2007, 46, 4389−4391.

(21) Hubbard, D. J.; Johnston, A. R.; Sanchez Casalongue, H.; Narducci Sarjeant, A.; Norquist, A. J. Inorg. Chem. 2008, 47, 8518− 8525.

(22) Choyke, S. J.; Blau, S. M.; Larner, A. A.; Narducci Sarjeant, A.; Yeon, J.; Halasyamani, P. S.; Norquist, A. J. Inorg. Chem. 2009, 48, 11277−11282.

(23) Monnier, A.; Schuth, F.; Huo, Q.; Kumar, D.; Margolese, D.; Maxwell, R. S.; Stucky, G. D.; Krishnamurty, M.; Petroff, P.; Firouzi, A.; Janicke, M.; Chmelka, B. F. Science 1993, 261, 1299−1303.

(24) Huo, Q.; Margolese, D. I.; Ciesla, U.; Feng, P.; Gier, T. E.; Sieger, P.; Leon, R.; Petroff, P. M.; Schueth, F.; Stucky, G. D. Nature 1994, 368, 317−321.

(25) Tolbert, S. H.; Landry, C. C.; Stucky, G. D.; Chmelka, B. F.; Norby, P.; Hanson, J. C.; Monnier, A. Chem. Mater. 2001, 13, 2247− 2256.

(26) El Haskouri, J.; Roca, M.; Cabrera, S.; Alamo, J.; Beltran-Porter, A.; Beltran-Porter, D.; Marcos, M. D.; Amoros, P. Chem. Mater. 1999, 11, 1446−1454.

(27) Casalongue, H. S.; Choyke, S. J.; Narducci Sarjeant, A.; Schrier, J.; Norquist, A. J. J. Solid State Chem. 2009, 182, 1297−1303.

(28) Chang, K. B.; Hubbard, D. J.; Zeller, M.; Schrier, J.; Norquist, A. J. Inorg. Chem. 2010, 49, 5167−5172.

(29) Koffer, J. H.; Olshansky, J. H.; Smith, M. D.; Hernandez, K. J.; Zeller, M.; Ferrence, G. M.; Schrier, J.; Norquist, A. J. Cryst. Growth Des. 2013, 13, 4504-4511.

(30) Olshansky, J. H.; Thao Tran, T.; Hernandez, K. J.; Zeller, M.; Halasyamani, P. S.; Schrier, J.; Norquist, A. J. Inorg. Chem. 2012, 51, 11040−11048.

(31) Smith, M. D.; Blau, S. M.; Chang, K. B.; Zeller, M.; Schrier, J.; Norquist, A. J. Cryst. Growth Des. 2011, 11, 4213−4219.

(32) Olshansky, J. H.; Blau, S. M.; Zeller, M.; Schrier, J.; Norquist, A. J. Cryst. Growth Des. 2011, 11, 3065−3071.

(33) Gutnick, J. R.; Muller, E. A.; Narducci Sarjeant, A.; Norquist, A. J. Inorg. Chem. 2004, 43, 6528−6530.

(34) Muller, E. A.; Cannon, R. J.; Narducci Sarjeant, A.; Ok, K. M.; Halasyamani, P. S.; Norquist, A. J. Cryst. Growth Des. 2005, 5, 1913− 1917.

(35) Bruker AXS Inc.: Madison, WI, USA, 2009.

(36) Altomare, A.; Cascarano, G.; Giacovazzo, C.; Guagliardi, A. J. Appl. Crystallogr. 1993, 26, 343−350.

(37) Betteridge, P. W.; Carruthers, J. R.; Cooper, R. I.; Prout, K.; Watkin, D. J. J. Appl. Crystallogr. 2003, 36, 1487.

(38) Dowty, E. Shape Software: Kingsport, TN, USA, 2002.

(39) Brown, I. D.; Altermatt, D. Acta Crystallogr., Sect. B 1985, 41, 244−247.

(40) Brese, N. E.; O'Keeffe, M. Acta Crystallogr., Sect. B 1991, 47, 192−197.

(41) Gonze, X.; Beuken, J. M.; Caracas, R.; Detraux, F.; Fuchs, M.; Rignanese, G. M.; Sindic, L.; Verstraete, M.; Zerah, G.; Jollet, F.; Torrent, M.; Roy, A.; Mikami, M.; Ghosez, P.; Raty, J. Y.; Allan, D. C. Comput. Mater. Sci. 2002, 25, 478−492.

(42) Gonze, X.; Amadon, B.; Anglade, P. M.; Beuken, J. M.; Bottin, F.; Boulanger, P.; Bruneval, F.; Caliste, D.; Caracas, R.; Cote, M.; Deutsch, T.; Genovese, L.; Ghosez, P.; Giantomassi, M.; Goedecker, S.; Hamann, D. R.; Hermet, P.; Jollet, F.; Jomard, G.; Leroux, S.; Mancini, M.; Mazevet, S.; Oliveira, M. J. T.; Onida, G.; Pouillon, Y.; Rangel, T.; Rignanese, G. M.; Sangalli, D.; Shaltaf, R.; Torrent, M.; Verstraete, M. J.; Zerah, G.; Zwanziger, J. W. Comput. Phys. Commun. 2009, 180, 2582−2615.

(43) Momma, K.; Izumi, F. J. Appl. Crystallogr. 2008, 41, 653−658. (44) Bultinck, P.; Van Alsenoy, C.; Ayers, P. W.; Carbo-Dorca, R. J.

Chem. Phys. 2007, 126, 144111.

(45) Bultinck, P.; Ayers, P. W.; Fias, S.; Tiels, K.; Van Alsenoy, C. Chem. Phys. Lett. 2007, 444, 205−208.

(46) Gaigalas, G.; Froese Fischer, C. Comput. Phys. Commun. 1996, 98, 255−264.

(47) Smith, M. D.; Blau, S. M.; Chang, K. B.; Tran, T. T.; Zeller, M.; Halasyamani, P. S.; Schrier, J.; Norquist, A. J. J. Solid State Chem. 2012, 195, 86−93.

(48) Chang, K. B.; Smith, M. D.; Blau, S. M.; Glor, E. C.; Zeller, M.; Schrier, J.; Norquist, A. J. Cryst. Growth Des. 2013, 13, 2190−2197.

(49) Engelen, B.; Boldt, K.; Unterderweide, K.; Baeumer, U. Z. Anorg. Allg. Chem. 1995, 621, 331−339.

(50) Micka, Z.; Nemec, I.; Vojtisek, P.; Ondracek, J. J. Solid State Chem. 1996, 122, 338−342.

(51) Dai, Z.; Li, G.; Shi, Z.; Fu, W.; Dong, W.; Xu, J.; Feng, S. Solid State Sci. 2004, 6, 91−96.

Inorganic Chemistry Article

(52) Norquist, A. J.; Doran, M. B.; O'Hare, D. Inorg. Chem. 2005, 44, 3837−3843.

- (53) Tudo, J.; Jolibois, B.; Laplace, G.; Nowogrocki, G.; Abraham, F. Acta Crystallogr., Sect. B 1979, B35, 1580−1583.
- (54) Chang, F. M.; Jansen, M.; Schmitz, D. Acta Crystallogr., Sect. C: Cryst. Struct. Commun. 1983, C39, 1497−1498.
- (55) Morris, R. E.; Harrison, W. T. A.; Stucky, G. D.; Cheetham, A. K. J. Solid State Chem. 1991, 94, 227−235.
- (56) Van Damme, S.; Bultinck, P.; Fias, S. J. Chem. Theory Comput. 2009, 5, 334−340.
- (57) Kim, J.-H.; Baek, J.; Halasyamani, P. S. Chem. Mater. 2007, 19, 5637−5641.
- (58) Maggard, P. A.; Nault, T. S.; Stern, C. L.; Poeppelmeier, K. R. J. Solid State Chem. 2003, 175, 27−33.
- (59) Izumi, H. K.; Kirsch, J. E.; Stern, C. L.; Poeppelmeier, K. R. Inorg. Chem. 2005, 44, 884−895.
- (60) Fabian, L.; Brock, C. P. Acta Crystallogr., Sect. B: Struct. Sci. 2010, B66, 94−103.